

United States Patent [19]

Nishizawa et al.

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[54] PHOTODIODE

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[73] Assignee: Sumitomo Electric Industries, Ltd., Osaka, Japan

[**] Term: 14 Years

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[30] Foreign Application Priority Data

Dec. 16, 1983 [JP] Japan 58-54296

[52] U.S. Cl. D13/99

[58] Field of Search D13/40, 41, 99; 174/52 R, 52 PE, 52 S; 357/30, 56, 58, 72, 74

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[57] CLAIM

The ornamental design for photodiode, as shown.

DESCRIPTION

FIG. 1 is a front, bottom and right side perspective view of a photodiode showing our new design; FIG. 2 is a front elevational view thereof; FIG. 3 is a top plan view thereof; FIG. 4 is a rear elevational view thereof; FIG. 5 is a left side elevational view thereof; and FIG. 6 is a right side elevational view thereof.

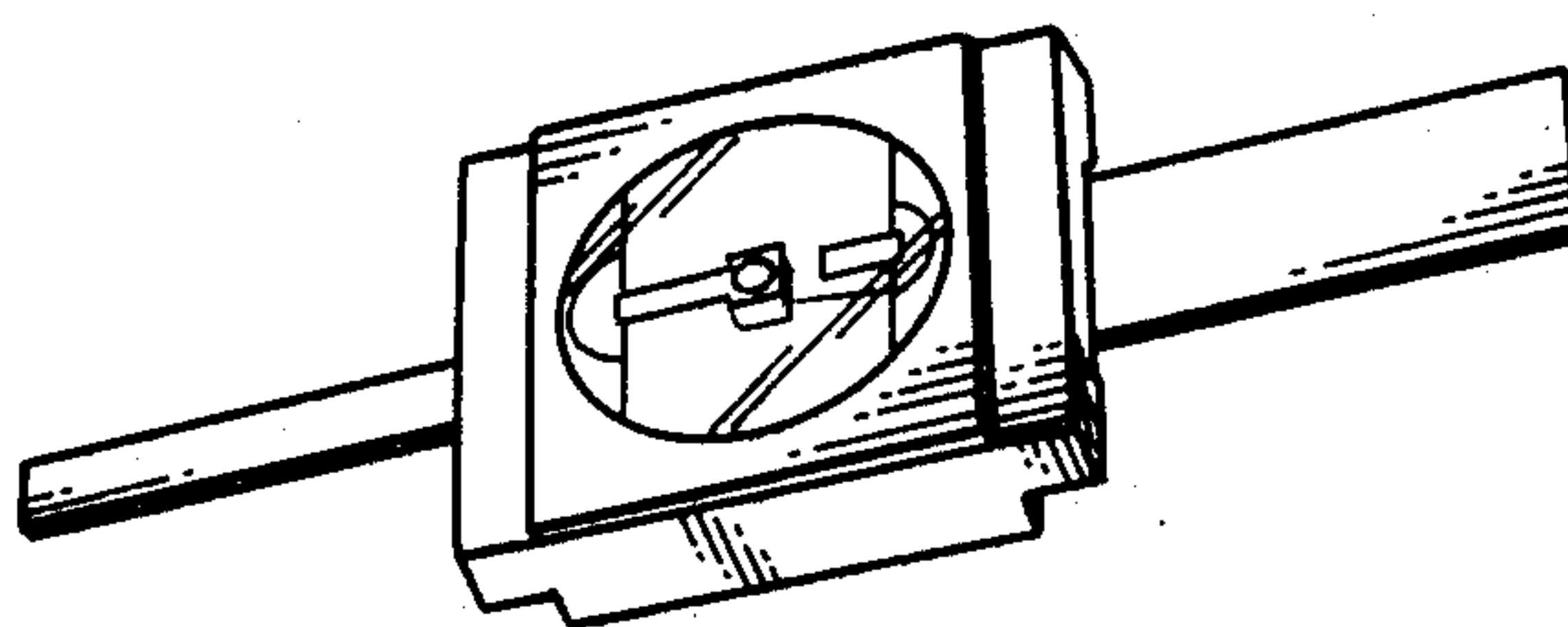


Fig. 1

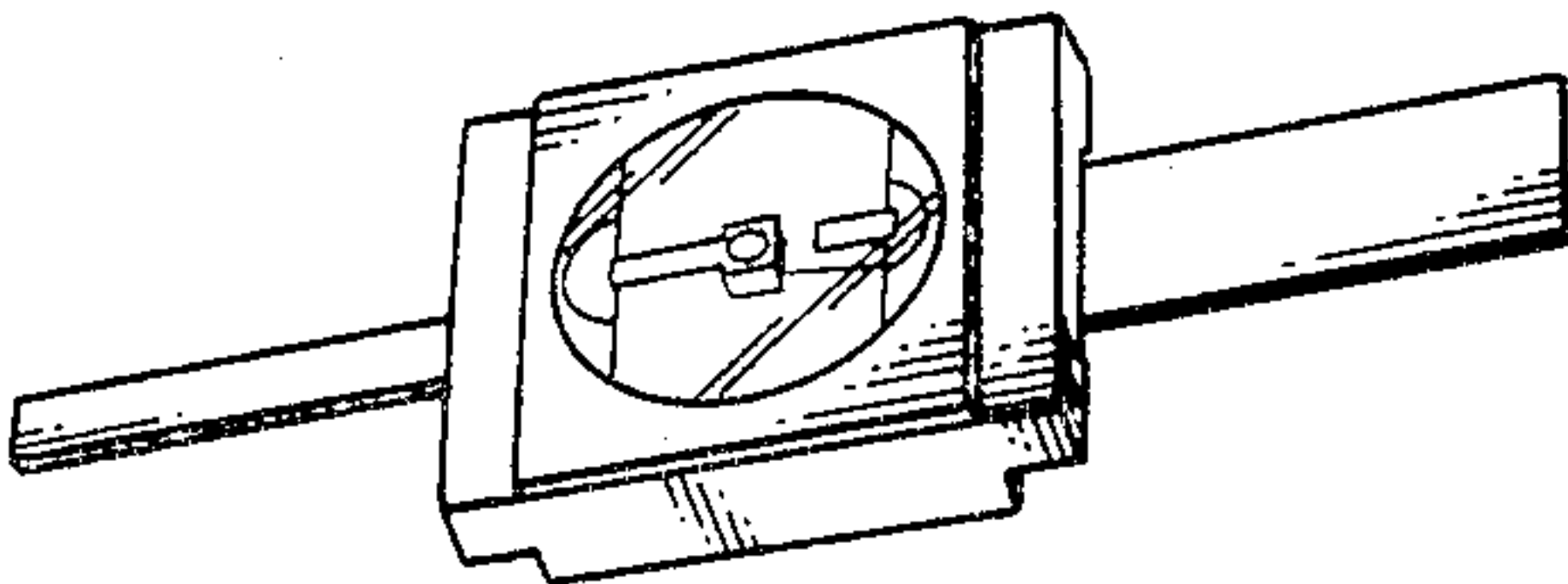


Fig. 2

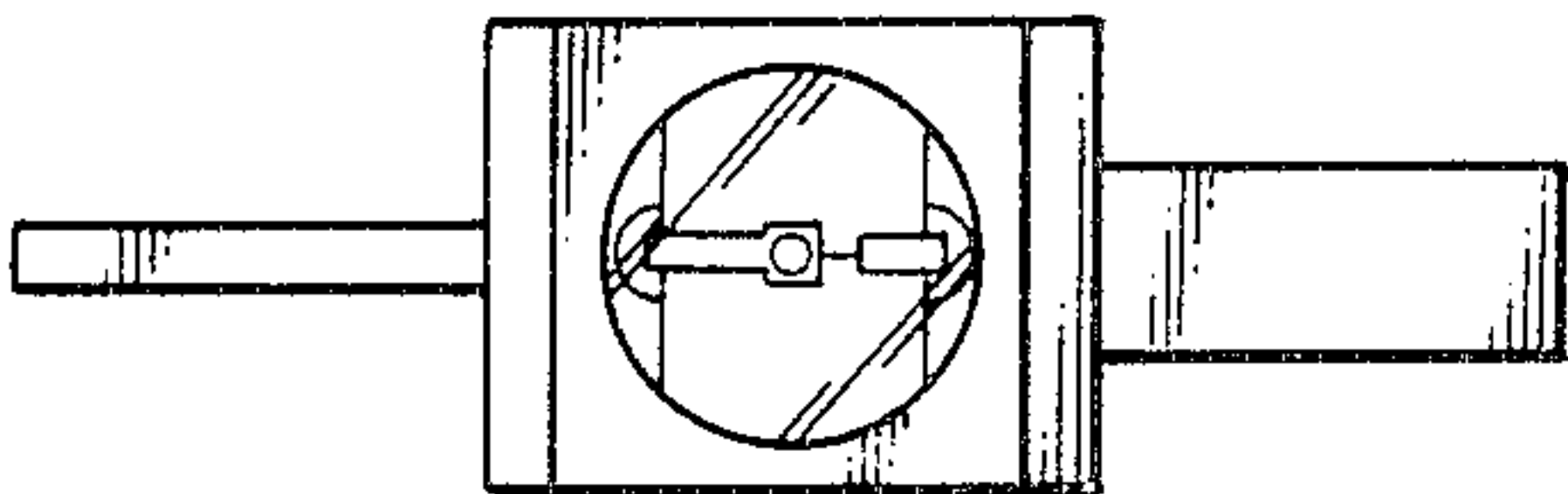


Fig. 5



Fig. 3



Fig. 4



Fig. 6

